

**Trans IGBT Chip N-CH 600V 8.5A 38mW 3-Pin(2+Tab) DPAK  
T/R**



Images are for reference only

<b>Manufacturer:</b>	<a href="#">Infineon Technologies Corporation</a>
<b>Package/Case:</b>	TO-252
<b>Product Type:</b>	Thyristors
<b>Lifecycle:</b>	Obsolete

[Inquiry](#)

## General Description

### Key Features

- UltraFast: Optimized for medium operating frequencies ( 8-40 kHz in hard switching, >200 kHz in resonant mode).
- Generation 4 IGBT design provides tighter parameter distribution and higher efficiency than previous generation
- IGBT co-packaged with HEXFRED™ ultrafast, ultra-soft-recovery anti-parallel diodes for use in bridge configurations
- Industry standard TO-252AA package



## Recommended For You

### IRG4PH50U

Infineon Technologies Corporation

TO-247

### IRGPC50F

Infineon Technologies Corporation

TO-247

### IRG4BC30W

Infineon Technologies Corporation

TO-220

**IRG4PC40U**

Infineon Technologies Corporation

TO-247

**IRGBC30F**

Infineon Technologies Corporation

TO-220

**IRG4PSC71K**

Infineon Technologies Corporation

TO-274AA

**IRG4PC30KD**

Infineon Technologies Corporation

TO-247

**IRG4PH30KD**

Infineon Technologies Corporation

TO-247

**IRG4PC30S**

Infineon Technologies Corporation

TO-247

**IRG4IBC30W**

Infineon Technologies Corporation

TO-220F

**IRGS14C40L**

Infineon Technologies Corporation

TO-263

**IRG4PC50UD**

Infineon Technologies Corporation

TO-247

**IRG4BC20UD**

Infineon Technologies Corporation

TO-220

**IRG4PC50U**

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**IRG4BC20KD**

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